



Zeners

1N746A - 1N759A

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------|---|-------------|-------|
| P_D | Power Dissipation | 500 | mW |
| T_{STG} | Storage Temperature Range | -65 to +200 | °C |
| T_J | Operating Junction Temperature | + 175 | °C |
| | Lead Temperature (1/16" from case for 10 seconds) | + 230 | °C |

*These ratings are limiting values above which the serviceability of the diode may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 200 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Tolerance: A = 5%



Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

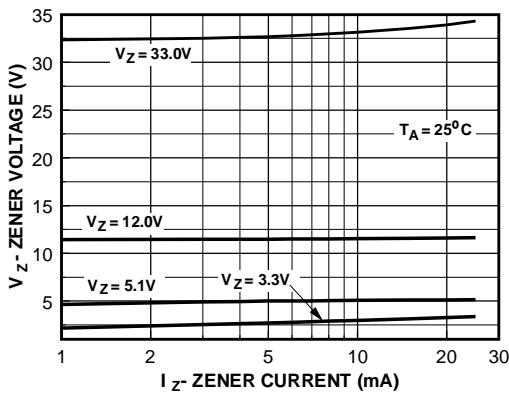
| Device | V_Z (V) | $Z_Z(\Omega)$ @ I_Z (mA) | $I_{R1}(\mu\text{A})$ @ V_R (V) | $I_{R2}(\mu\text{A})$ @ V_R (V) | $T_A = 150^\circ\text{C}$ | V_R (V) | T_C (%/°C) | I_{ZRM}^* (mA) |
|--------|-----------|----------------------------|-----------------------------------|-----------------------------------|---------------------------|-----------|--------------|------------------|
| 1N746A | 3.3 | 28 | 20 | 10 | 1.0 | 30 | - 0.070 | 110 |
| 1N747A | 3.6 | 24 | 20 | 10 | 1.0 | 30 | - 0.065 | 100 |
| 1N748A | 3.9 | 23 | 20 | 10 | 1.0 | 30 | - 0.060 | 95 |
| 1N749A | 4.3 | 22 | 20 | 2.0 | 1.0 | 30 | +/- 0.055 | 85 |
| 1N750A | 4.7 | 19 | 20 | 2.0 | 1.0 | 30 | +/- 0.030 | 75 |
| 1N751A | 5.1 | 17 | 20 | 1.0 | 1.0 | 20 | +/- 0.030 | 70 |
| 1N752A | 5.6 | 11 | 20 | 1.0 | 1.0 | 20 | + 0.038 | 65 |
| 1N753A | 6.2 | 7.0 | 20 | 0.1 | 1.0 | 20 | + 0.045 | 60 |
| 1N754A | 6.8 | 5.0 | 20 | 0.1 | 1.0 | 20 | + 0.050 | 55 |
| 1N755A | 7.5 | 6.0 | 20 | 0.1 | 1.0 | 20 | + 0.058 | 50 |
| 1N756A | 8.2 | 8.0 | 20 | 0.1 | 1.0 | 20 | + 0.062 | 45 |
| 1N757A | 9.1 | 10 | 20 | 0.1 | 1.0 | 20 | + 0.068 | 40 |
| 1N758A | 10 | 17 | 20 | 0.1 | 1.0 | 20 | + 0.075 | 35 |
| 1N759A | 12 | 30 | 20 | 0.1 | 1.0 | 20 | + 0.077 | 38 |

* I_{ZRM} (Maximum Zener Current Rating) Values shown are based on the JEDEC rating of 400 milliwatts. Where the actual zener voltage (V_Z) is known at the operating point, the maximum zener current may be increased and is limited by the derating curve.

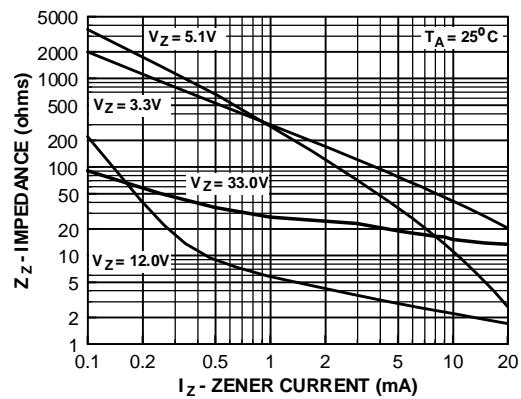
Zeners (1N746A - 1N759A)

Zeners (1N746A - 1N759A) (continued)

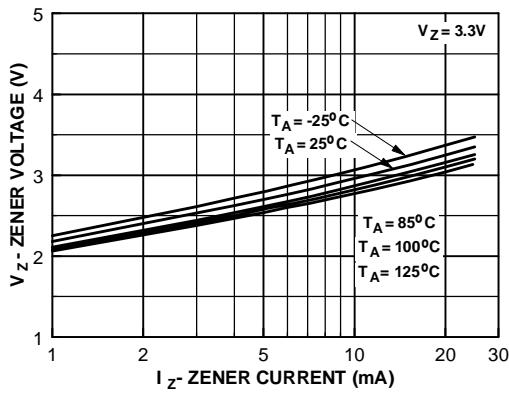
Typical Characteristics



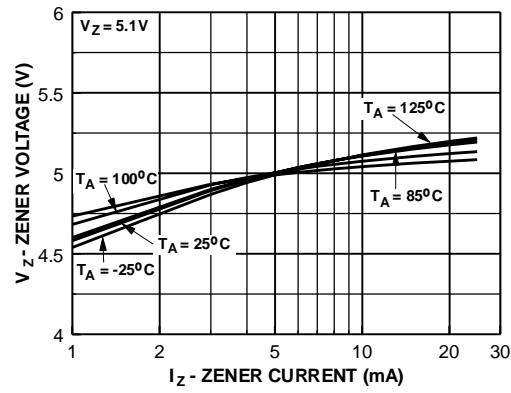
Zener Current vs. Zener Voltage



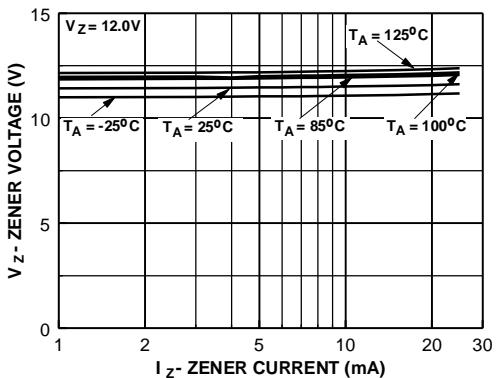
Zener Current vs. Zener Impedance



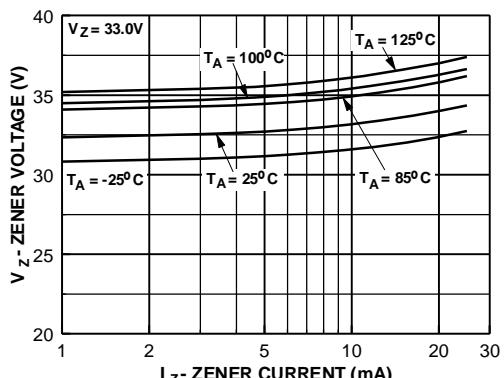
3.3 Zener Voltage vs. Temperature



5.1 Zener Voltage vs. Temperature



12 Zener Voltage vs. Zener Temperature



33 Zener Voltage vs. Zener Temperature

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